

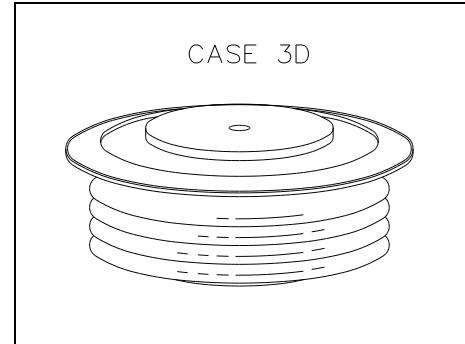
POSITIONING PSTA641 - Standard Rectifier

1500 - 2600
V_{RRM}; 1500 A avg

GENERAL PURPOSE HIGH POWER STANDARD RECTIFIER

Features:

- . All Diffused Structure
- . High Surge rating
- . Blocking capability up to 2600 volts
- . Soft Reverse Recovery
- . Rugged Ceramic Hermetic Package
- . Pressure Assembled Device



ELECTRICAL CHARACTERISTICS AND RATINGS

Reverse Blocking

Device Type	V _{RRM} (1)	V _{RSM} (1)
PSTA641PE	1500	1600
PSTA641PM	1600	1700
PSTA641PN	1800	1900
PSTA641L	2000	2100
PSTA641LB	2200	2300
PSTA641LD	2400	2500
PSTA641LM	2600	2700

 V_{RRM} = Repetitive peak reverse voltage

 V_{RSM} = Non repetitive peak reverse voltage (2)

Repetitive peak reverse leakage	I _{RRM}	20 mA
		70 mA (3)

Notes:

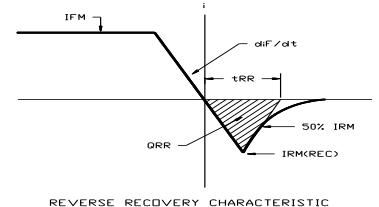
All ratings are specified for T_j=25 °C unless otherwise stated.

(1) All voltage ratings are specified for an applied 50Hz/60Hz sinusoidal waveform over the temperature range -40 to +185 °C.

(2) 10 msec. max. pulse width

(3) Maximum value for T_j = 185 °C.

(4) See parameter definition below :



Conducting - on state

Parameter	Symbol	Min.	Max.	Typ.	Units	Conditions
Average value of on-state current	I _{F(AV)}		1500		A	Sinewave, 180° conduction, T _c =90°C
RMS value of on-state current	I _{FRMS}		2350		A	Nominal value
Peak one cycle surge (non repetitive) current	I _{FSM}		16000		A	8.3 msec (60Hz), sinusoidal wave-shape, 180° conduction, T _j = 185 °C
			14500		A	10.0 msec (50Hz), sinusoidal wave-shape, 180° conduction, T _j = 185 °C
I square t	I ² t		1.06x10 ⁶		A ² s	8.3 msec and 10.0 msec
Peak on-state voltage	V _{FM}		1.65		V	I _{FM} = 4700 A; T _j = 160 °C
Reverse Recovery Current (4)	I _{RM(REC)}	*		160	A	I _{FM} = 1000 A; dI _F /dt = 10 A/μs; 125 °C
Reverse Recovery Charge (4)	Q _{rr}	*			μC	
Reverse Recovery Time (4)	t _{RR}	*			μs	

Technical

Data : AD-029

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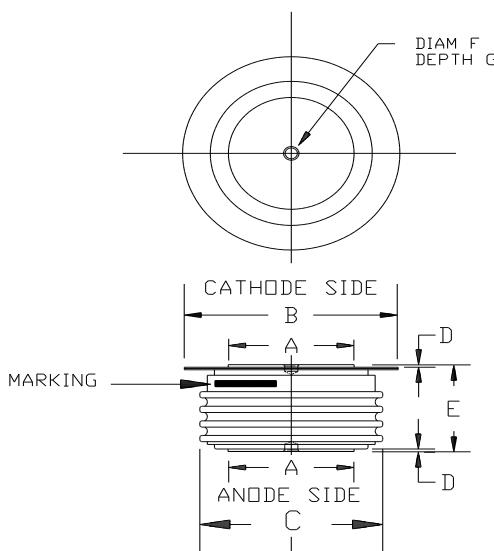
THERMAL AND MECHANICAL CHARACTERISTICS Rectifier

PSTA641 - Standard

Parameter	Symb ol	Min.	Max.	Typ.	Units	Conditions
Operating temperature	T _j	-40	+185		°C	
Storage temperature	T _{stg}	-40	+185		°C	
Thermal resistance - junction to case	R _{θ(j-c)}		0.040 0.080		°C/W	Double sided cooled Single sided cooled
Thermal resistance - case to sink	R _{θ(c-s)}		.015 .030		°C/W	Double sided cooled * Single sided cooled *
Mounting force	P	3500	4500 19.9		lb. kN	
Weight	W			9 225	oz. g	

* Mounting surfaces smooth, flat and
greased

CASE OUTLINE AND DIMENSIONS.



OUTLINE DIMENSIONS - CASE 3D				
DIMENSIONS	Min. mm	Max. mm	Min. In.	Max. In.
DIAM A	33.02	34.29	1.30	1.35
DIAM B	55.88	63.50	2.20	2.50
DIAM C	--	54.61	--	2.15
D	0.76	--	0.03	--
E	25.40	27.18	1.00	1.07
F	3.30	3.81	0.13	0.15
G	1.78	2.03	0.07	0.08

STRIKE DISTANCE = .73 INCH / 18.5 MM MIN.
CREEPAGE DISTANCE = 1.17 INCH / 29.7 MM MIN.